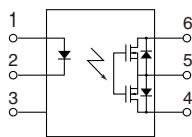
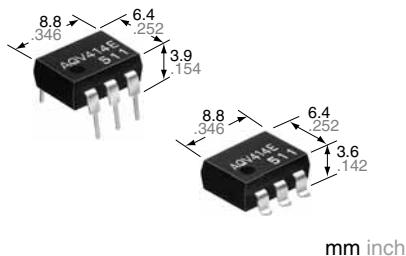


**Normally closed type
with reinforced insulation**

**PhotoMOS®
GE 1 Form B
(AQV414E, AQV410EH)**

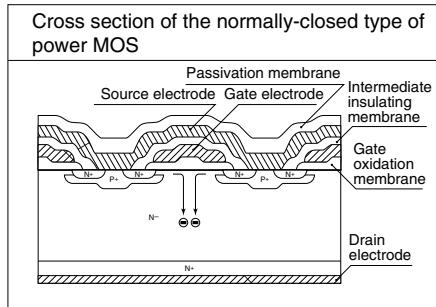
FEATURES



RoHS compliant

1. **1 Form B output type**
2. **60V type couples high capacity (0.55A) with low on-resistance (typ. 1Ω).**
3. **Low on-resistance**

This has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.



4. **Controls low-level analog signals**
PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

5. **High sensitivity and low on-resistance**

Can control max. 0.55 A load current with 5 mA input current.
Low on-resistance of typ. 1Ω (AQV412EH).

6. **Low-level off-state leakage current of max. 1 μA (AQV414E)**

7. **Reinforced insulation 5,000 V type also available**

More than 0.4 mm internal insulation distance between inputs and outputs.
Conforms to EN41003, EN60950 (reinforced insulation).

TYPICAL APPLICATIONS

- Power supply
- Measuring equipment
- Security equipment
- Telephone equipment
- Sensing equipment

TYPES

I/O isolation voltage	Output rating*		Package	Part No.				Packing quantity
				Through hole terminal		Surface-mount terminal		
	Load voltage	Load current		Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	
AC/DC dual use	1,500 V AC (Standard)	400 V 120 mA	DIP6-pin	AQV414E	AQV414EA	AQV414EAX	AQV414EAZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.
	60 V	550 mA		AQV412EH	AQV412EHA	AQV412EHAX	AQV412EHAZ	
	350 V	130 mA		AQV410EH	AQV410EHA	AQV410EHAX	AQV410EHAZ	
	400 V	120 mA		AQV414EH	AQV414EHA	AQV414EHAX	AQV414EHAZ	

*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

GE 1 Form B (AQV414E, AQV410EH)

RATING

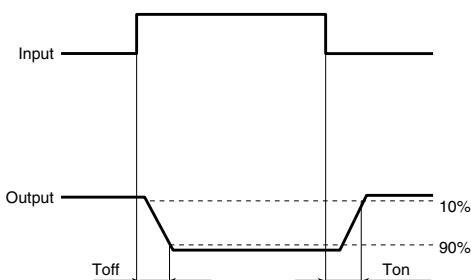
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item	Symbol	Type of connection	AQV414E(A)	AQV412EH(A)	AQV410EH(A)	AQV414EH(A)	Remarks			
Input	LED forward current	I _F	50 mA							
LED reverse voltage	V _R		5 V							
Peak forwd current	I _{FP}		1 A				f = 100 Hz, Duty factor = 0.1%			
Power dissipation	P _{in}		75 mW							
Output	Load voltage (peak AC)	V _L	400 V	60 V	350 V	400 V				
	Continuous load current	I _L	A	0.12 A	0.55 A	0.13 A	0.12 A			
			B	0.13 A	0.65 A	0.15 A	0.13 A			
			C	0.15 A	0.8 A	0.17 A	0.15 A			
	Peak load current	I _{peak}		0.3 A	1.5 A	0.4 A	0.3 A			
Total power dissipation	Power dissipation	P _{out}	500 mW							
			550 mW							
			1,500 V AC	5,000 V AC						
Temperature limits	Operating	T _{opr}	−40°C to +85°C							
	Storage	T _{stg}	−40°C to +100°C				−40°F to +212°F			

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item	Symbol	Type of connection	AQV414E(A)	AQV412EH(A)	AQV410EH(A)	AQV414EH(A)	Condition	
Input	LED operate (OFF) current	Typical	I _{Foff}	—	1.45 mA	1.9 mA	I _L = Max.	
		Maximum		3.0 mA				
	LED reverse (ON) current	Minimum	I _{Fon}	—	0.3 mA	0.4 mA	I _L = Max.	
		Typical		1.40 mA				
Output	LED dropout voltage	Typical	V _F	A	1.25 V (1.14 V at I _F = 5 mA)		I _F = 50 mA	
		Maximum			1.5 V			
		Typical		B	26 Ω	1 Ω	18 Ω	25.2 Ω
		Maximum			50 Ω	2.5 Ω	35 Ω	50 Ω
	On resistance	Typical	R _{on}	B	20 Ω	0.55 Ω	13 Ω	19 Ω
		Maximum			25 Ω	1.3 Ω	17.5 Ω	25 Ω
	Off state leakage current	Typical	R _{on}	C	10 Ω	0.3 Ω	6.5 Ω	10 Ω
		Maximum			12.5 Ω	0.7 Ω	8.8 Ω	12.5 Ω
Transfer characteristics	Operate (OFF) time*	Typical	T _{off}	—	0.7 ms	3 ms	1.5 ms	1.3 ms
	Operate (OFF) time*	Maximum		2.0 ms			8 ms	3.0 ms
	Reverse (ON) time*	Typical	T _{on}	—	0.1 ms	0.3 ms		
		Maximum		1.0 ms			1.5 ms	
	I/O capacitance	Typical	C _{iso}	—	0.8 pF			f = 1 MHz
	I/O capacitance	Maximum		1.5 pF			V _B = 0 V	
Initial I/O isolation resistance		Minimum	R _{iso}	—	1,000 MΩ			500 V DC

*Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I _F	Standard type: 5 Reinforced type: 5 to 10	mA

■ These products are not designed for automotive use.

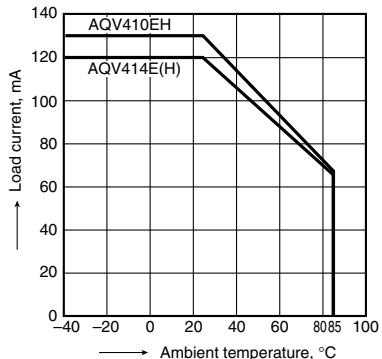
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$
 -40°F to $+185^{\circ}\text{F}$

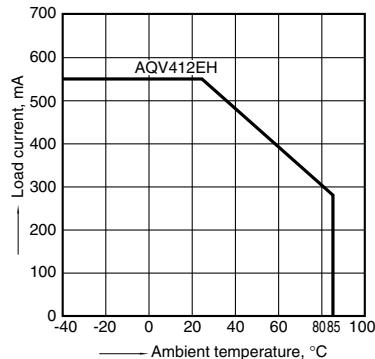
Type of connection: A



1-(2). Load current vs. ambient temperature characteristics

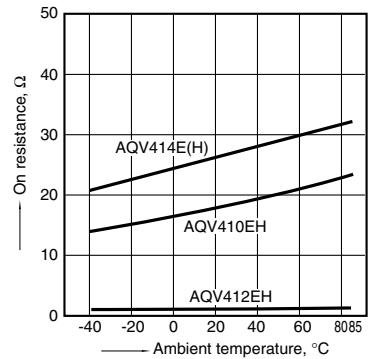
Allowable ambient temperature: -40°C to $+85^{\circ}\text{C}$
 -40°F to $+185^{\circ}\text{F}$

Type of connection: A



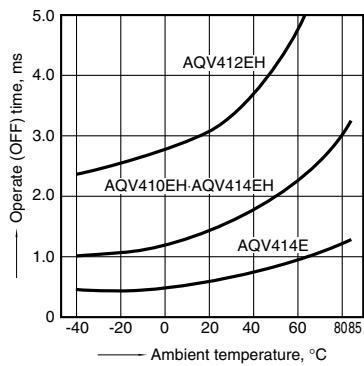
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 0 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



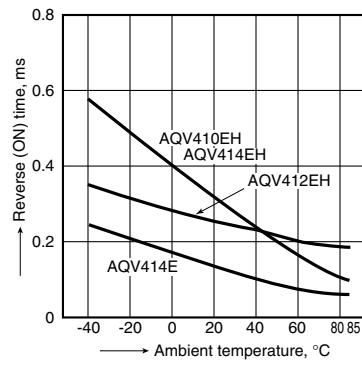
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



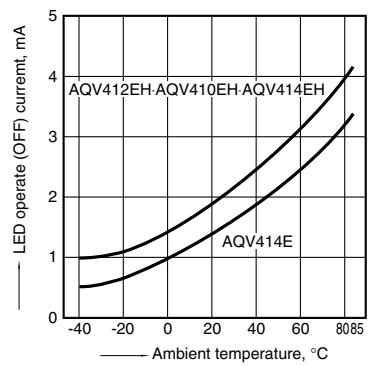
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



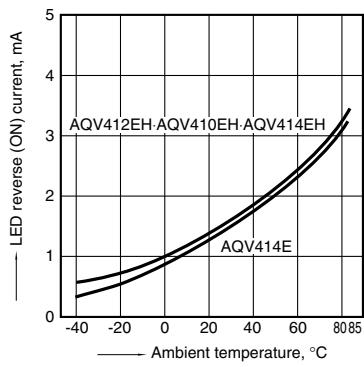
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



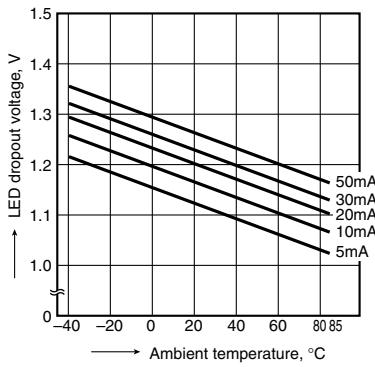
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



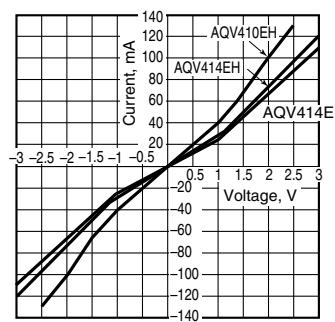
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types;
LED current: 5 to 50 mA



8-(1). Current vs. voltage characteristics of output at MOS portion

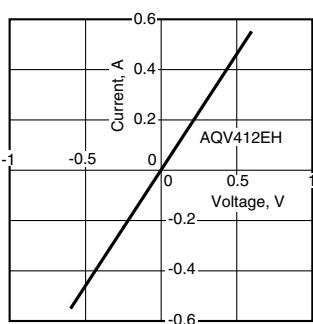
Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



GE 1 Form B (AQV414E, AQV410EH)

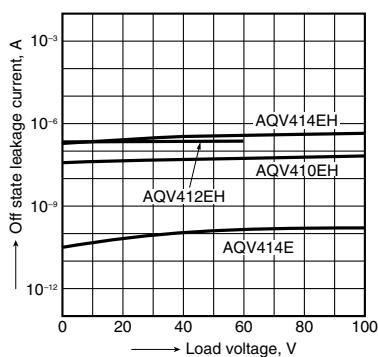
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



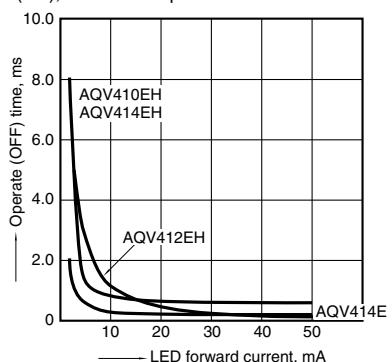
9. Off state leakage current vs. load voltage characteristics

Sample: All types;
Measured portion: between terminals 4 and 6;
LED current: 5 mA; Ambient temperature: 25°C 77°F



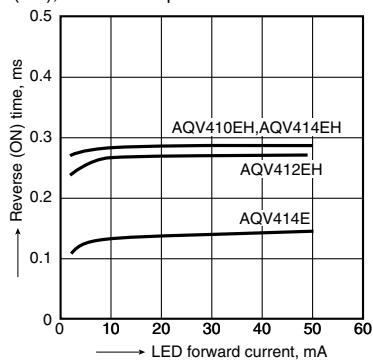
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz;
Ambient temperature: 25°C 77°F

